

DIO32051A

0.5 MHz, 24 μ A, High Performance CMOS Amplifier

Features

- Max offset (V_{OS}): DIO32051A at ± 3 mV
- Unity gain stable
- Gain bandwidth product: 0.5 MHz
- Wide supply range: 1.8 V to 5.5 V
- Input voltage range: 0 V to 5 V
- Ultra low power: 24 μ A
- Compact package best for portable applications

DIO32051A: DFN0.8*0.8-4

Applications

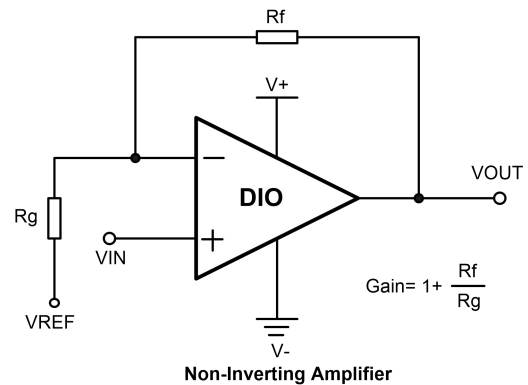
- ASIC input or output amplifiers
- Sensor interfaces
- Audio output
- Portable systems
- Notebook PCs
- Battery-powered equipment

Descriptions

The DIO32051A is a high performance CMOS operational amplifier with ultra low offset. Features include wide input common-mode voltage range and broad output voltage swing with operating supply voltage from 1.8 V to 5.5 V. Product is fully specified over the extended -40 to $+125^{\circ}\text{C}$ temperature range.

The DIO32051A provides 0.5 MHz bandwidth consuming an ultra-low current of 24 μ A. Featuring very low input bias current. It is ideal for integrators and photodiode amplifiers.

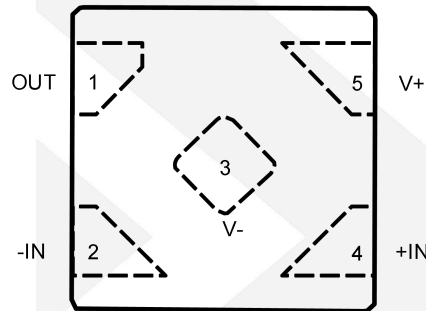
Typical Application



Ordering Information

Order Part Number	Top Marking		T _A	Package	
DIO32051ACN4	U	RoHS or Green	-40 to +125°C	DFN0.8*0.8-4	Tape & Reel, 5000

Pin Assignments



DFN0.8*0.8-4

Figure 1. Pin Assignment (Top View)

Pin Description

Pin name	Description
V+	Positive supply
V-	Negative supply
+IN	Positive Input
-IN	Negative Input
OUT	Output

Absolute Maximum Ratings

Stresses beyond those listed under the Absolute Maximum Rating table may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other condition beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Symbol	Parameter	Rating	Unit
V_{CC}	Supply Voltage	7	V
V_{IN}	Input Voltage	(V ₋)-0.1 to 7	V
T_{STG}	Storage Temperature Range	-65 to 150	°C
T_J	Junction Temperature	150	°C
T_L	Lead Temperature Range	260	°C
ESD	HBM, JEDEC: JESD22-A114	8	kV
	CDM, JEDEC: JESD22-C101	2	

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. DIOO does not recommend exceeding them or designing to absolute maximum ratings.

Symbol	Parameter	Rating	Unit
V_{CC}	Supply Voltage	1.8 to 5.5	V
V_{IN}	Input Voltage	0 to V ₊	V
T_A	Operating Temperature Range	-40 to 125	°C

Electrical Characteristics

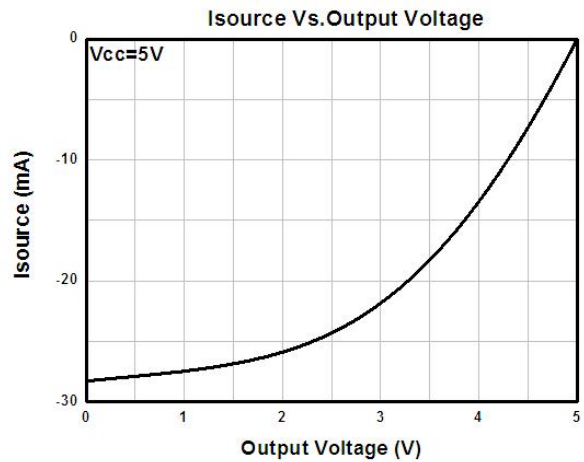
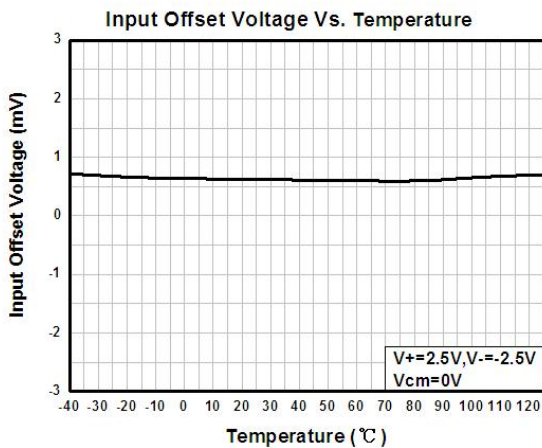
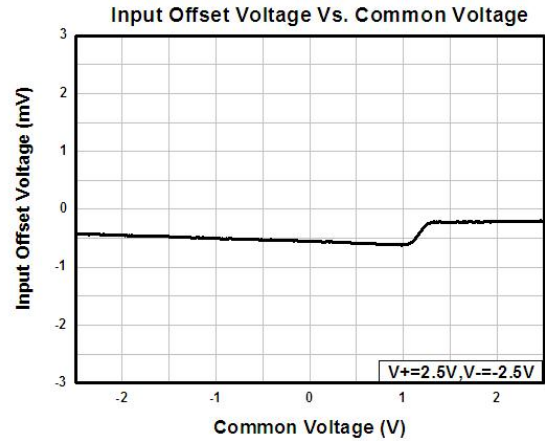
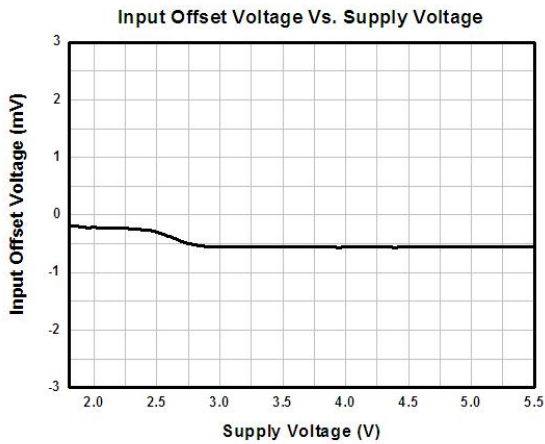
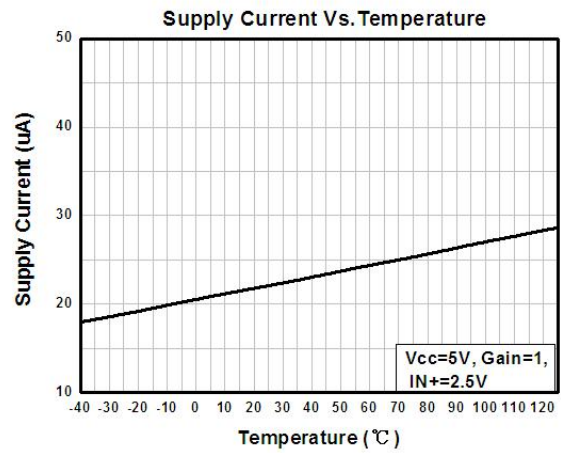
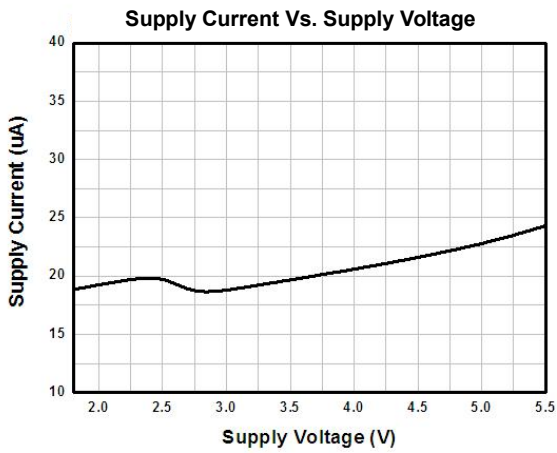
Typical value: $V_+ = 5\text{ V}$, $R_L = 100\text{ k}\Omega$ to $V_+/2$, $T_A = 25^\circ\text{C}$, unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Input characteristics						
V_{OS}	Input offset voltage	$-40^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$, $V_+ = 1.8\text{ V to } 5\text{ V}$	-3	0	3	mV
I_B	Input bias current	$-40^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$, $V_+ = 1.8\text{ V to } 5\text{ V}$		20		pA
I_{OS}	Input offset current	$-40^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$, $V_+ = 1.8\text{ V to } 5\text{ V}$		5		pA
V_{CM}	Common mode voltage range		0.1		V_+	V
CMRR	Common mode rejection ratio	$-40^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$, $V_{CM} = 0.1\text{ to } V_+$		75		dB
A_{OL}	Open loop voltage gain	$R_L = 5\text{ k}\Omega$, $V_O = 0.1\text{ to } (V_+) - 0.1$	80	102		dB
		$R_L = 200\text{ k}\Omega$, $V_O = 0.1\text{ to } (V_+) - 0.1$	100	128		
d_{VOS}/dt	Input offset voltage drift	$-40^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$			2.5	$\mu\text{V}/^\circ\text{C}$
Output characteristics						
V_{OH}	Output voltage high	$V_+ = 5\text{ V}$, $R_L = 100\text{ k}\Omega$, $-40^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$		4.995		V
		$V_+ = 1.8\text{ V}$, $R_L = 100\text{ k}\Omega$, $-40^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$		1.79		
V_{OL}	Output voltage low	$V_+ = 5\text{ V}$, $R_L = 100\text{ k}\Omega$, $-40^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$		5		mV
		$V_+ = 1.8\text{ V}$, $R_L = 100\text{ k}\Omega$, $-40^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$		5		
I_{SC}	Output short circuit current	Source I_{SC} , $V_+ = 5\text{ V}$		28		mA
		Sink I_{SC} , $V_+ = 5\text{ V}$		28		
Power supply						
PSRR	Power supply rejection ration		65	85		dB
I_S	Supply current	$-40^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$		24		μA
Dynamic performance						
GBP	Gain bandwidth product	$R_L = 100\text{ K}$, $C_L = 100\text{ pF}$		0.5		MHz
SR	Slew rate	$G=1$, 2 V output step		0.29		V/ μs
t_S	Setting time	$G=1$, 2 V output step		4		μs
Noise performance						
THD	Total harmonic distortion	$f = 10\text{ kHz}$, 2 V output step, $R_L = 10\text{ k}\Omega$		0.02		%
e_n	Voltage noise density	$f = 1\text{ kHz}$		66		nV/ $\sqrt{\text{Hz}}$
		$f = 10\text{ kHz}$		54		

Specifications subject to change without notice.

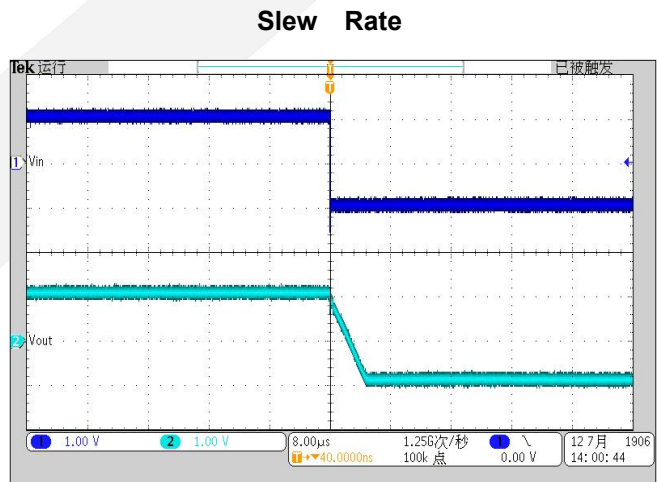
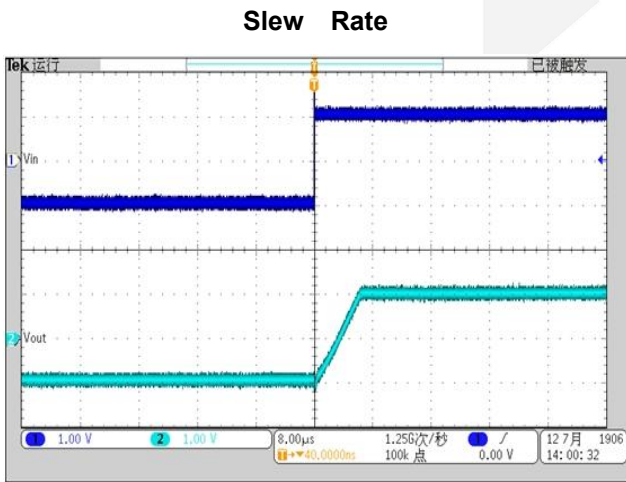
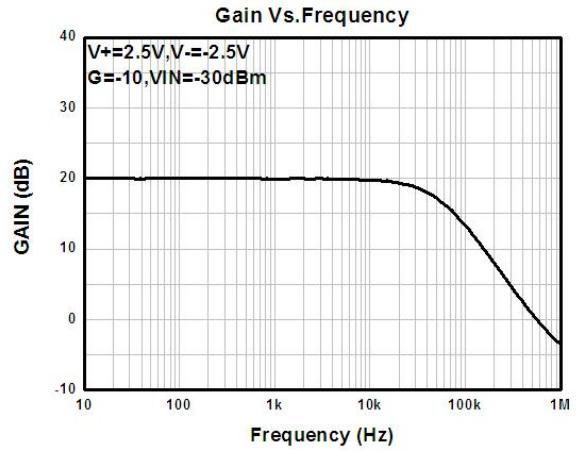
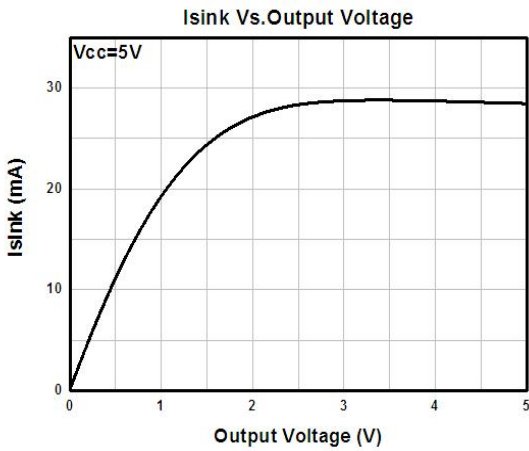
Typical Performance Characteristics

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CONTACT US

Dioo is a professional design and sales corporation for high-quality and performance analog semiconductors. The company focuses on industry markets, such as cell phones, handheld products, laptops, medical equipment, and so on. Dioo's product families include analog signal processing and amplifying, LED drivers, and charger ICs. Go to <http://www.dioo.com> for a complete list of Dioo product families.

For additional product information or full datasheet, please contact our sales department or representatives.

